## 



LIBRARY Brainware University Barasat, Kolkata -700125

## **BRAINWARE UNIVERSITY**

Term End Examination 2022

## Programme – B.Tech.(CSE)-AIML-2021/B.Tech.(CSE)-DS-2021/B.Tech.(CSE)-AIML-2022 **Course Name – Semi-Conductor Physics** Course Code - BSCM101/BSCD101

(Semester I)

Full Marks : 60

Time : 2:30 Hours [The figure in the margin indicates full marks. Candidates are required to give their answers in their own

words as far as practicable.]

Group-A				
	(Multiple Choice Type Question)			
1. Choose the correct alternative from the following :				
(i)	) With forward bias to a pn junction, the width of depletion layer			
(ii)	a) decreases c) remains the same Considering the mass-action law in semicondu correct option at the thermal equilibrium. (Sym			
	a) $n/p = constant$	b) $np = n_i^2$		
	c) $n > \frac{n_i^2}{p}$	d) $n < \frac{n_i^2}{p}$		
(iii)	<ul> <li>For the semiconductors with an indirect bandgap identify the correct statement from the following.</li> </ul>			
	<ul> <li>a) Materials for which minimum of valence band and maximum of conduction band do not occur at same value of k</li> <li>c) Materials for which maximum of valence band and minimum of conduction band</li> </ul>	d) Materials for which maximum of		
(iv)	occurs at same value of $k$ With the increase of temperature, an extrinsic	band and minimum of conduction not occur at same value of k semiconductor behaves as	band do	
	a) conductor c) intrinsic semiconductor	b) insulator		
(v)	c) intrinsic semiconductor d) superconductor Which of the following is not an assumption in Drude-Lorentz theory of free electrons?			
	<ul> <li>a) Metals contain free electrons that move through a lattice of positive ions</li> </ul>	<ul> <li>b) Electric field produced by lattice ions considered to be uniform throughou and hence neglected</li> </ul>		
	c) Free electrons in a metal resemble	d) The electrons are distributed among	the	

Page 1 of 4

Brainware Universit Barasat, Kolkola -700120 energy levels according to Pauli's exclusion molecules of a gas and therefore the laws of kinetic theory of gases are applicable to principle free electrons (vi) The resistivity of a material depends on which of the following factors: a) length of the conductor b) area of cross section of the conductor c) temperature d) mass of the material (vii) Express Wiedemann-Franz law in a correct form as a)  $\frac{\sigma_T}{\sigma} = LT$ b)  $\frac{\sigma}{\sigma_T} = LT$ c)  $\frac{\sigma_T}{\sigma} = \frac{L}{T}$  $\frac{d}{\sigma_{T}} = \frac{T}{L}$ (viii) In Relativistic case, as the velocity of the particle approaches the speed of light, the predicted Kinetic energy will approach a) zero b) non-relativistic kinetic energy c) rest mass energy d) Infinite (ix) Population inversion in preparing laser beam can be achieved a) when one of the excited states is less b) when one of the excited states is more populated than the ground state populated than the ground state c) when the population of one excited state d) on the basis of none of the above and the ground state are equal conditions (x) The shape of E-K diagram of the conduction band and valance band is predicted to he a) horizontal b) vertical c) circle d) parabolic (xi) No two electrons will have all the four quantum numbers equal. This statement is proposed as a) Uncertainty principle b) Pauli exclusion principle c) Hund's rule d) Aufbau's principle (xii) At 0 K temperature, semiconductors are a) Perfect metals b) Perfect non-metals c) Perfect insulator d) Perfect conductor (xiii) Identify the total energy operator. a)  $-i\hbar \frac{\partial}{\partial t}$ b)  $i\hbar \frac{\partial}{\partial t}$ c)  $-\hbar \frac{\partial}{\partial t}$ d)  $\hbar \frac{\partial}{\partial t}$ (xiv) Merit of four point probe method of determining resistivity is that a) it gives the resistivity at a localized region b) it injects excess minority carriers of the sample d) it gives the average resistivity of the c) it needs very small current sample (xv) Identify the correct relation between total energy [E] and temperature [T] in Stefan-Boltzmann law a)  $E \propto T^4$ b)  $E \propto T^{-4}$ d)  $E \propto T^{-1}$ c)  $E \propto T$ 

Group-B

(Short Answer Type Questions)

3 x 5=15

2. Construct the expression of the effective mass of electron based on the Kronig-Penny Mode	el. (3)
3. Explain the terms acceptance angle and numerical aperture in connection to an optical fiber	: (3)
4. Describe the physical interpretation of wave function in quantum mechanics. <sup>5.</sup> Solve the normalization constant $a$ if the wave function has the following form	(3) (3)
$\psi(x) = a \sin \frac{\pi x}{L}$ , for $0 \le x \le L$	
= 0, otherwise LIBRARY Brainware Uni OR Barasat, Kolkata	versity
OR Barasat, Kolkein	.,
Write down the differences between avalanche and Zener breakdown.	(3)
	(-)
6. Distinguish between direct and indirect band gap semiconductors.	(3)
OR Evaluate the de-Broglie wavelength of an electron moving with velocity 0.6c. [hint: use relativistic corrections]	(3)
Group-C	
(Long Answer Type Questions)	5 x 6=30
7. What do you mean by meta-stable state? Explain the working principle of laser.	(5)
8. Explain attenuation in optical fibre by illustrating different mechanism responsible for it.	(5)
9. Deduce Stefan's law from Planck's radiation formula.	(5)
<ol> <li>Write down Schrödinger's equation for one-dimensional motion for a free particle in a one dimensional potential box. Appling appropriate boundary conditions calculate its eigen energies.</li> </ol>	- (5)
<ol> <li>Compare the assumptions of classical free-electron theory (Drude-Lorentz theory) and quantum free electron theory.</li> </ol>	(5)
<b>OR</b> The E-k relationship for electrons in a hypothetical energy band is given by, $E(k) = E_0$ [1- exp(-2a <sup>2</sup> k <sup>2</sup> )], where a is lattice constant. Calculate the effective mass at k=0.	(5)

0

C

12. Justify that the sum of the probability of occupancy of an energy state at  $\Delta E$  above the Fermi (5) level and that at  $\Delta E$  below the Fermi level is unity.

OR The electrons are allowed to pass through a crystal with lattice constant 0.1 nm. Estimate the (5) uncertainty in its velocity.

Brahware Line and the second s